

60HQ... SERIES

SCHOTTKY RECTIFIER

60 Amp

Major Ratings and Characteristics

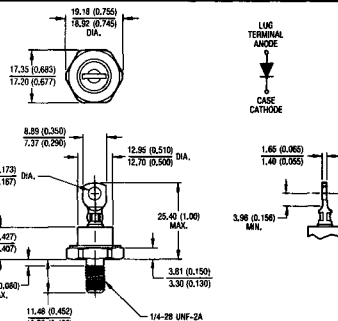
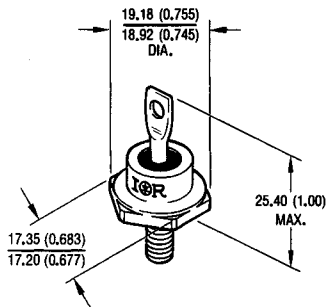
Characteristics	60HQ...	Units
$I_{F(AV)}$ Rectangular waveform	60	A
V_{RRM}	80 to 100	V
I_{FSM} @ $t_p = 5 \mu s$ sine	8400	A
V_F @ 60 Apk, $T_J = 125^\circ C$	0.70	V
T_J	-55 to 175	$^\circ C$

Description/Features

The 60HQ Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to $175^\circ C$ junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- $175^\circ C$ T_J operation
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Hermetic packaging

CASE STYLE AND DIMENSIONS



Conforms to JEDEC Outline DO-203AB (DO-5)

Dimensions in millimeters and inches

Voltage Ratings

Part number	60HQ080	60HQ100
V_R Max. DC Reverse Voltage (V)	80	100
V_{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters	60HQ	Units	Conditions		
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	60	A	50% duty cycle @ $T_C = 118^{\circ}\text{C}$, rectangular wave form		
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	8400	A	5 μs Sine or 3 μs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied	
	1200		10ms Sine or 6ms Rect. pulse		
E_{AS} Non-Repetitive Avalanche Energy	15	mJ	$T_J = 25^{\circ}\text{C}$, $I_{AS} = 1$ Amps, $L = 30$ mH		
I_{AR} Repetitive Avalanche Current	1	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical		

Electrical Specifications

Parameters	60HQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.95	V	@ 60A $T_J = 25^\circ\text{C}$
	1.15	V	@ 120A
	0.77	V	@ 60A $T_J = 125^\circ\text{C}$
	0.97	V	@ 120A
I_{RM} Max. Reverse Leakage Current (1) * See Fig. 2	5	mA	$T_J = 25^\circ\text{C}$
	25	mA	$T_J = 125^\circ\text{C}$ $V_R = \text{rated } V_R$
C_T Max. Junction Capacitance	1400	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	7.5	nH	Measured from top of terminal to mounting plane
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs	

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	60HQ	Units	Conditions
T_J Max. Junction Temperature Range	-55 to 175	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 175	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case	0.83	$^\circ\text{C/W}$	DC operation * See Fig. 4
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.25	$^\circ\text{C/W}$	Mounting surface, smooth and greased
wt Approximate Weight	15 (0.53)	g (oz.)	
T Mounting Torque	Min. 23 (20)	Kg-cm (lbf-in)	Non-lubricated threads
	Max. 46 (40)		
Case Style	DO-203AB(DO-5)		JEDEC

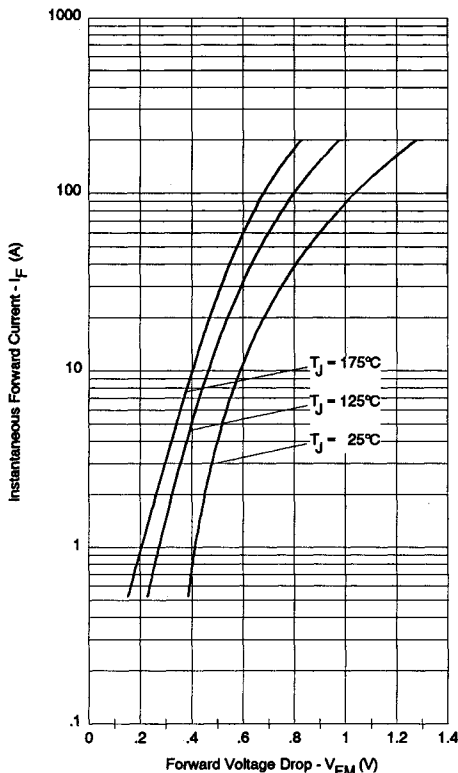


Fig. 1 - Maximum Forward Voltage Drop Characteristics

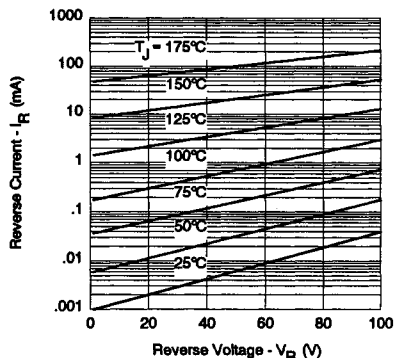


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

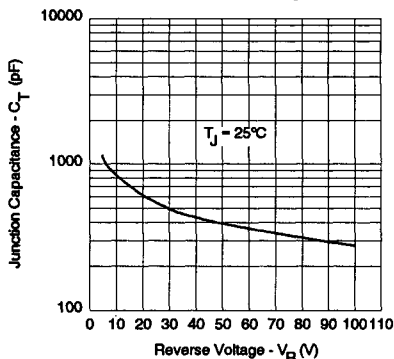
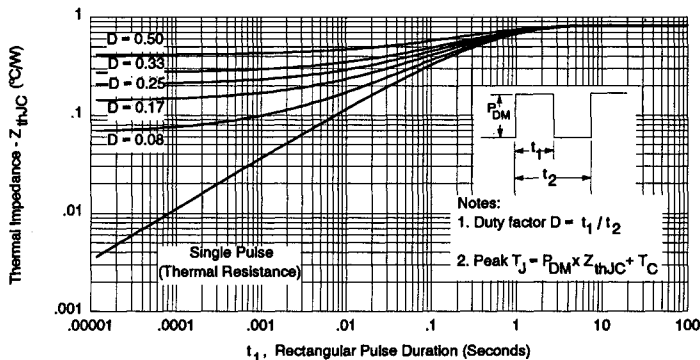


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage


Fig. 4 - Maximum Thermal Impedance $Z_{\theta JC}$ Characteristics

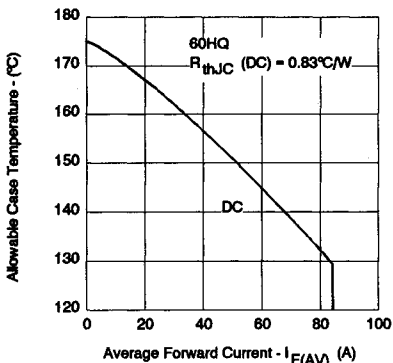


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

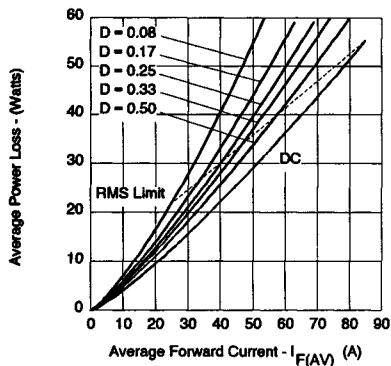


Fig. 6 - Forward Power Loss Characteristics

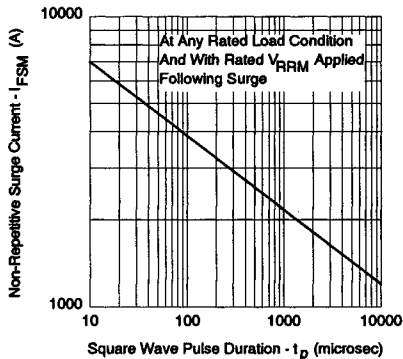


Fig. 7 - Maximum Non-Repertive Surge Current

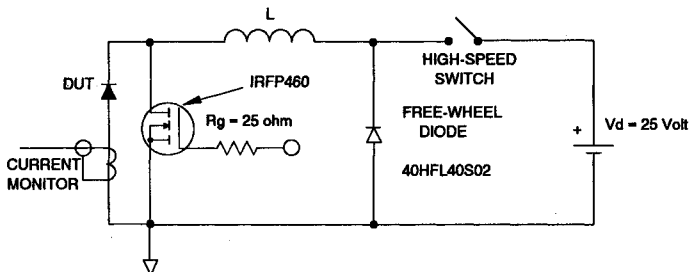


Fig. 8 - Unclamped Inductive Test Circuit